- **Supports Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})**

- **Supports Unregulated Battery Operation Down to 2.7 V**

- **Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C**

- **I_{off} and Power-Up 3-State Support Hot Insertion**

- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**

- **ESD Protection Exceeds JESD 22**
  - **2000-V Human-Body Model (A114-A)**
  - **200-V Machine Model (A115-A)**
  - **1000-V Charged-Device Model (C101)**

DB, DW, NS, OR PW PACKAGE
(TOP VIEW)

DIR	1	20	V_{CC}
A1	2	19	$\overline{OE}$
A2	3	18	B1
A3	4	17	B2
A4	5	16	B3
A5	6	15	B4
A6	7	14	B5
A7	8	13	B6
A8	9	12	B7
GND	10	11	B8

RGY PACKAGE
(TOP VIEW)

A1	2	19	$\overline{OE}$
A2	3	18	B1
A3	4	17	B2
A4	5	16	B3
A5	6	15	B4
A6	7	14	B5
A7	8	13	B6
A8	9	12	B7

DIR 1 V_{CC} 20
GND 10   B8 11
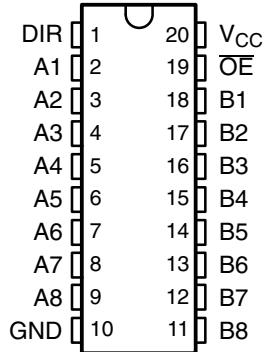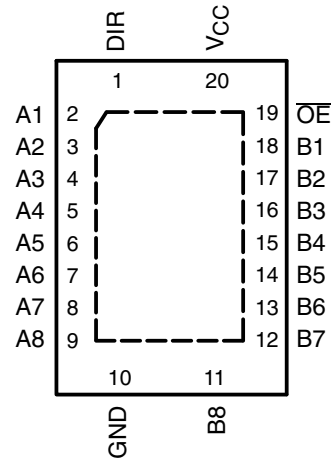
description/ordering information

This octal bus transceiver is designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The SN74LVT245B is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ($\overline{OE}$) input can be used to disable the device so the buses are effectively isolated.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 85°C	QFN – RGY	Tape and reel	SN74LVT245BRGYR	LX245B
	SOIC – DW	Tube	SN74LVT245BDW	LVT245B
		Tape and reel	SN74LVT245BDWR	
	SOP – NS	Tape and reel	SN74LVT245BNSR	LVT245B
	SSOP – DB	Tape and reel	SN74LVT245BDBR	LX245B
	TSSOP – PW	Tube	SN74LVT245BPW	LX245B
		Tape and reel	SN74LVT245BPWR	
	VFBGA – GQN	Tape and reel	SN74LVT245BGQNR	LX245B
	VFBGA – ZQN (Pb-free)		SN74LVT245BZQNR	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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TEXAS INSTRUMENTS

description/ordering information (continued)

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.
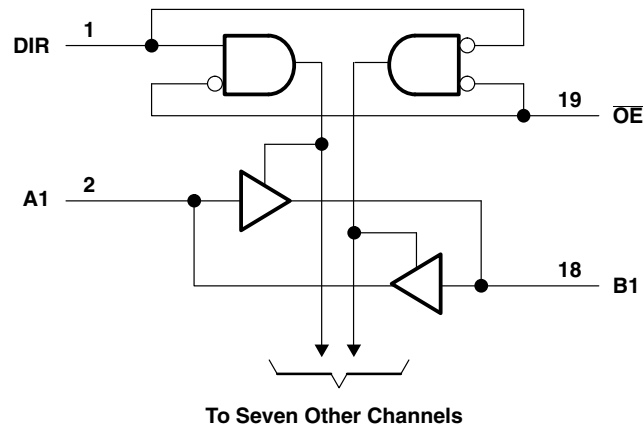
GQN OR ZQN PACKAGE
(TOP VIEW)
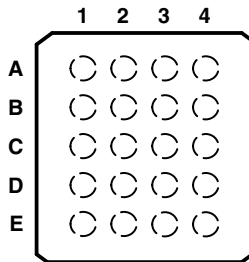
terminal assignments

	1	2	3	4
A	A1	DIR	V_{CC}	$\overline{OE}$
B	A3	B2	A2	B1
C	A5	A4	B4	B3
D	A7	B6	A6	B5
E	GND	A8	B8	B7

FUNCTION TABLE

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

logic diagram (positive logic)

To Seven Other Channels

Pin numbers shown are for the DB, DW, NS, PW, and RGY packages.

TEXAS
INSTRUMENTS

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . –0.5 V to 4.6 V

Input voltage range, V_I (see Note 1) . . . . –0.5 V to 7 V

Voltage range applied to any output in the high-impedance
  or power-off state, V_O (see Note 1) . . . . –0.5 V to 7 V

Voltage range applied to any output in the high state, V_O (see Note 1) . . . . –0.5 V to V_{CC} + 0.5 V

Current into any output in the low state, I_O . . . . 128 mA

Current into any output in the high state, I_O (see Note 2) . . . . 64 mA

Input clamp current, I_{IK} (V_I < 0) . . . . –50 mA

Output clamp current, I_{OK} (V_O < 0) . . . . –50 mA

Package thermal impedance, θ_{JA} (see Note 3): DB package . . . . 70°C/W
                          (see Note 3): DW package . . . . 58°C/W
                          (see Note 3): GQN/ZQN package . . . . 78°C/W
                          (see Note 3): NS package . . . . 60°C/W
                          (see Note 3): PW package . . . . 83°C/W
                          (see Note 4): RGY package . . . . 37°C/W

Storage temperature range, T_{stg} . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and
  functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not
  implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
        2. This current flows only when the output is in the high state and V_O > V_{CC}.
        3. The package thermal impedance is calculated in accordance with JESD 51-7.
        4. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 5)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2.7	3.6	V
V_{IH}	High-level input voltage		2		V
V_{IL}	Low-level input voltage			0.8	V
V_I	Input voltage			5.5	V
I_{OH}	High-level output current			–32	mA
I_{OL}	Low-level output current			64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		µs/V
T_A	Operating free-air temperature		–40	85	°C

NOTE 5: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report,
        Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}		V_{CC} = 2.7 V,	I_I = –18 mA			–1.2	V
V_{OH}		V_{CC} = 2.7 V to 3.6 V,	I_{OH} = –100 μA	V_{CC}–0.2			V
		V_{CC} = 2.7 V,	I_{OH} = –8 mA	2.4			
		V_{CC} = 3 V,	I_{OH} = –32 mA	2			
V_{OL}		V_{CC} = 2.7 V	I_{OL} = 100 μA			0.2	V
			I_{OL} = 24 mA			0.5	
		V_{CC} = 3 V	I_{OL} = 16 mA			0.4	
			I_{OL} = 32 mA			0.5	
			I_{OL} = 64 mA			0.55	
I_I	Control inputs	V_{CC} = 3.6 V,	$V_I = V_{CC}$ or GND			±1	μA
		V_{CC} = 0 or 3.6 V,	V_I = 5.5 V			10	
	A or B ports‡	V_{CC} = 3.6 V	V_I = 5.5 V			20	
			$V_I = V_{CC}$			1	
			V_I = 0			–5	
I_{off}		V_{CC} = 0,	V_I or V_O = 0 to 4.5 V			±100	μA
I_{OZH}		V_{CC} = 3.6 V,	V_O = 3 V			5	μA
I_{OZL}		V_{CC} = 3.6 V,	V_O = 0.5 V			–5	μA
I_{OZPU}		V_{CC} = 0 to 1.5 V, V_O = 0.5 V to 3 V, $\overline{OE}$ = don't care				±100	μA
I_{OZPD}		V_{CC} = 1.5 V to 0, V_O = 0.5 V to 3 V, $\overline{OE}$ = don't care				±100	μA
I_{CC}		V_{CC} = 3.6 V, I_O = 0, $V_I = V_{CC}$ or GND	Outputs high			0.19	mA
			Outputs low			5	
			Outputs disabled			0.19	
ΔI_{CC}§		V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND				0.2	mA
C_i		V_I = 3 V or 0			4		pF
C_{io}		V_O = 3 V or 0			9		pF

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
‡ Unused terminals are at V_{CC} or GND.
§ This is the increase in supply current for each input that is at the specified TTL-voltage level, rather than V_{CC} or GND.
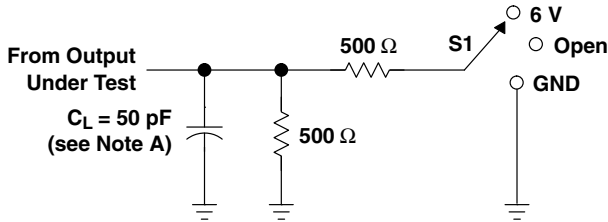
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 3.3 V ± 0.3 V			V_{CC} = 2.7 V		UNIT
			MIN	TYP†	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	1.2	2.3	3.5		4	ns
t_{PHL}			1.2	2.1	3.5		4	
t_{PZH}	$\overline{OE}$	A or B	1.3	3.2	5.5		7.1	ns
t_{PZL}			1.7	3.4	5.5		6.5	
t_{PHZ}	$\overline{OE}$	A or B	2.2	3.5	5.9		6.5	ns
t_{PLZ}			2.2	3.4	5		5.1	

† All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

TEXAS
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PARAMETER MEASUREMENT INFORMATION

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND

LOAD CIRCUIT
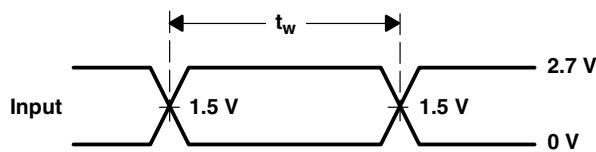
VOLTAGE WAVEFORMS
PULSE DURATION
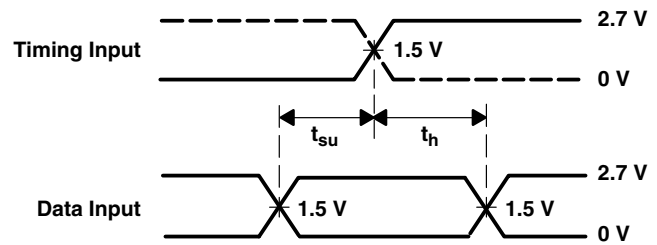
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES

VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS
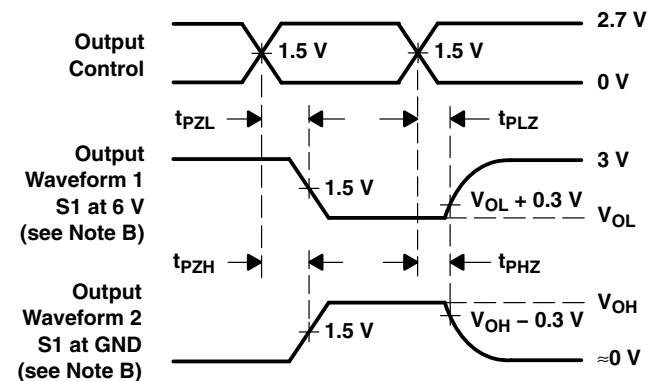
VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

TEXAS
INSTRUMENTS

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
SN74LVT245BDBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI
SN74LVT245BDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BGQNR	NRND	BGA MICROSTAR JUNIOR	GQN	20	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74LVT245BNSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BNSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BNSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPWLE	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI
SN74LVT245BPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVT245BRGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74LVT245BRGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74LVT245BZQNR	ACTIVE	BGA MICROSTAR JUNIOR	ZQN	20	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVT245BDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVT245BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LVT245BGQNR	BGA MICROSTAR JUNIOR	GQN	20	1000	330.0	12.4	3.3	4.3	1.5	8.0	12.0	Q1
SN74LVT245BNSR	SO	NS	20	2000	330.0	24.4	8.2	13.0	2.5	12.0	24.0	Q1
SN74LVT245BPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVT245BRGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
SN74LVT245BZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	330.0	12.4	3.3	4.3	1.5	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVT245BDBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN74LVT245BDWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN74LVT245BGQNR	BGA MICROSTAR JUNIOR	GQN	20	1000	346.0	346.0	29.0
SN74LVT245BNSR	SO	NS	20	2000	346.0	346.0	41.0
SN74LVT245BPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
SN74LVT245BRGYR	VQFN	RGY	20	3000	346.0	346.0	29.0
SN74LVT245BZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	346.0	346.0	29.0

GQN (R–PBGA–N20)   PLASTIC BALL GRID ARRAY
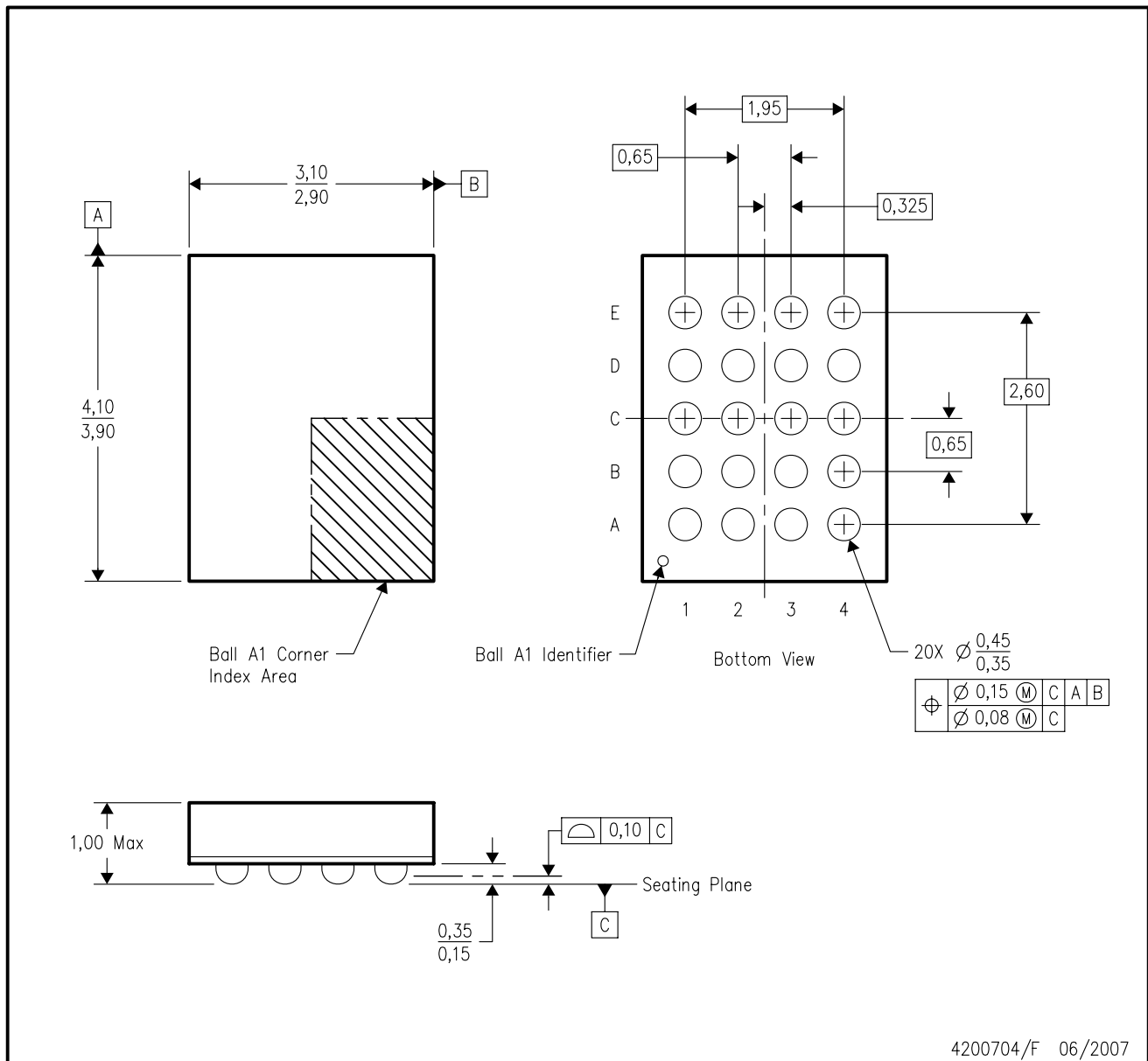
3,10 / 2,90 — B

A

4,10 / 3,90

Ball A1 Corner
Index Area

1,95

0,65

0,325

E D C B A

2,60

0,65

1 2 3 4

Ball A1 Identifier

Bottom View

20X ⌀ 0,45 / 0,35

⊕	⌀ 0,15 Ⓜ	C	A	B
	⌀ 0,08 Ⓜ	C		

1,00 Max

0,10 C

Seating Plane

0,35 / 0,15

C

4200704/F 06/2007

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
        B. This drawing is subject to change without notice.
        C. Falls within JEDEC MO–285 variation BC–2.
        D. This package is tin–lead (SnPb). Refer to the 20 ZQN package (drawing 4204492) for lead–free.

ZQN (R−PBGA−N20)   PLASTIC BALL GRID ARRAY
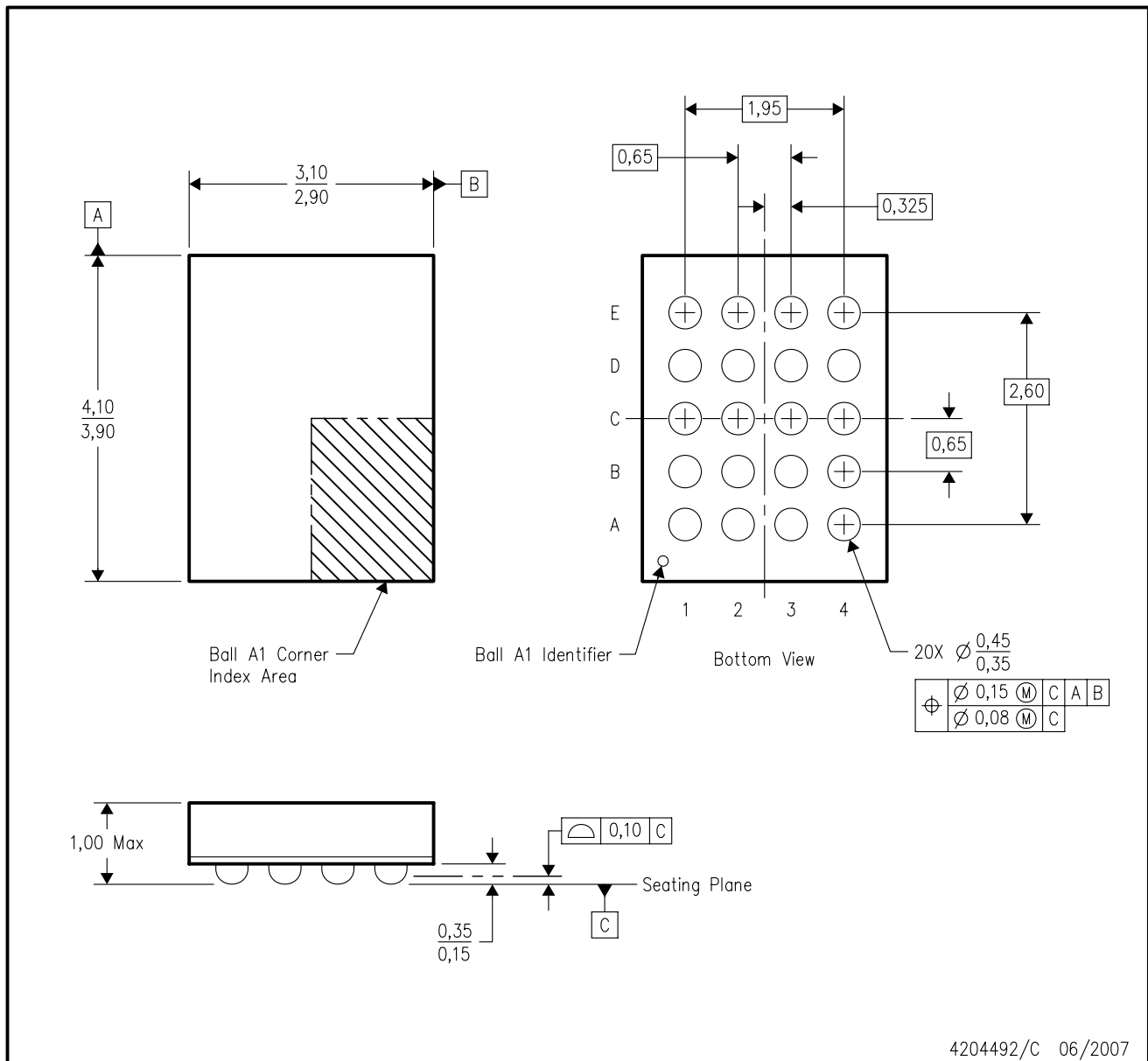
3,10
2,90

A

4,10
3,90

Ball A1 Corner
Index Area

1,95

0,65

0,325

E D C B A

2,60

0,65

1 2 3 4

Ball A1 Identifier   Bottom View

20X Ø 0,45 / 0,35

| Ø 0,15 Ⓜ | C | A | B |
| Ø 0,08 Ⓜ | C |

1,00 Max

0,10 C

Seating Plane

0,35
0,15

C

4204492/C 06/2007

NOTES: A.   All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
         B.   This drawing is subject to change without notice.
         C.   Falls within JEDEC MO−285 variation BC−2.
         D.   This package is lead−free. Refer to the 20 GQN package (drawing 4200704) for tin−lead (SnPb).

DW (R−PDSO−G20)　　　　　PLASTIC SMALL−OUTLINE PACKAGE

$\dfrac{0.512\ (13,00)}{0.496\ (12,60)}$

20

11

$\dfrac{0.419\ (10,63)}{0.393\ (9,97)}$

$\dfrac{0.299\ (7,60)}{0.291\ (7,40)}$

1

10

Pin 1
Index Area

0.050 (1,27)

$\dfrac{0.020\ (0,51)}{0.012\ (0,31)}$

⊕ | 0.010 (0,25) Ⓜ

0.104 (2,65) Max

$\dfrac{0.012\ (0,30)}{0.004\ (0,10)}$

$\dfrac{0.013\ (0,33)}{0.008\ (0,20)}$

Gauge Plane

0.010 (0,25)

0°−8°

⌒ | 0.004 (0,10)

Seating Plane

$\dfrac{0.050\ (1,27)}{0.016\ (0,40)}$
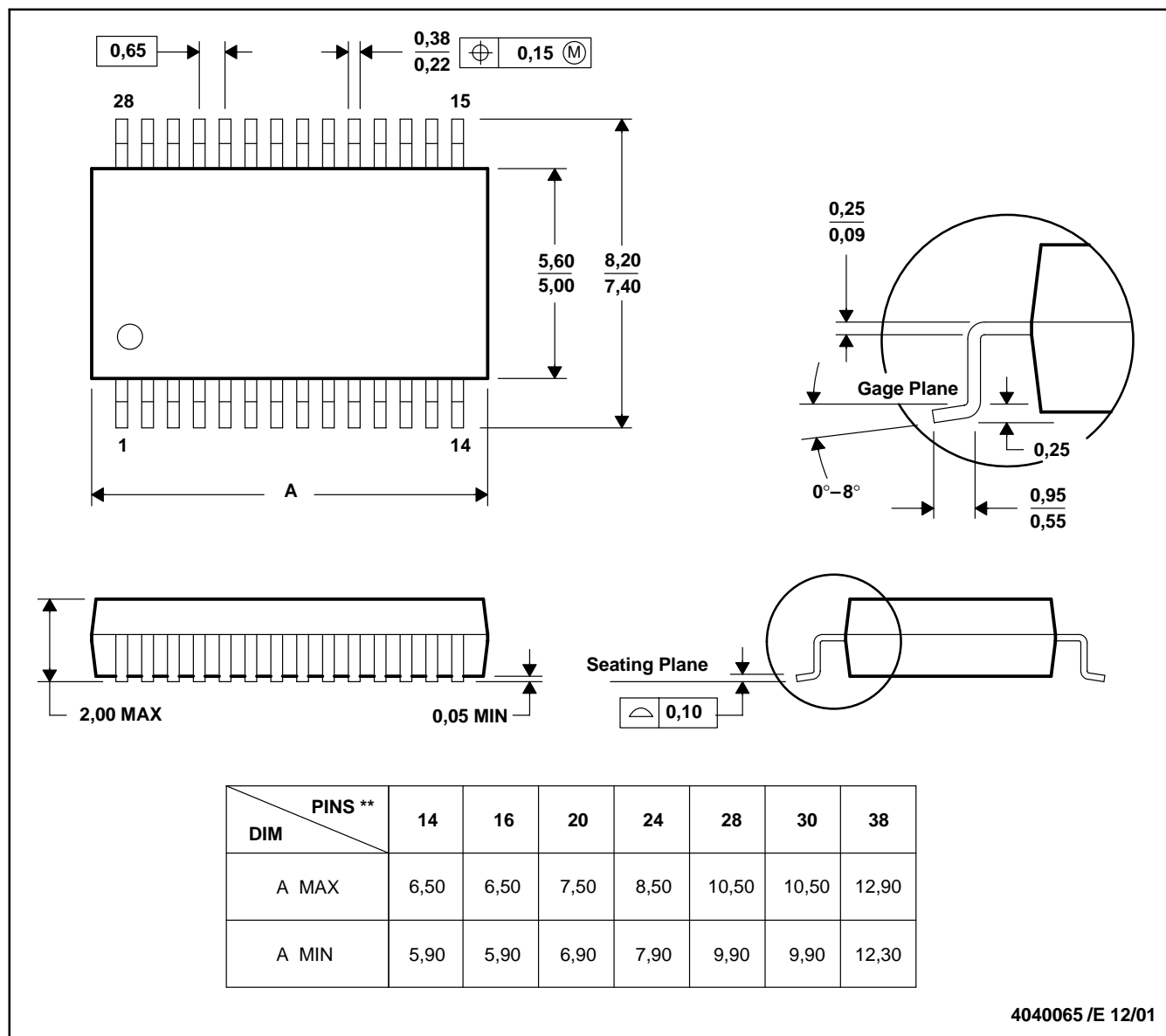
4040000−4/F 06/2004

NOTES:　A.　All linear dimensions are in inches (millimeters).
　　　　　B.　This drawing is subject to change without notice.
　　　　　C.　Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
　　　　　D.　Falls within JEDEC MS−013 variation AC.

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RGY (R−PVQFN−N20) PLASTIC QUAD FLATPACK NO−LEAD

4,65 / 4,35 A

B

19 12

20 11

3,65 / 3,35

1 10

Pin 1 Index Area
Top and Bottom
E

2 9

0,20 Nominal
Lead Frame

1,00 / 0,80

Seating Plane

0,08 C

0,05 / 0,00
Seating Height
C

3,50

0,50

20X 0,50 / 0,30

2 9

1 10

1,50

11

20

20X 0,30 / 0,18

Exposed Thermal Pad
D

19 12

+0,10

⊕ 0,10 Ⓜ C A B
0,05 Ⓜ C

Bottom View
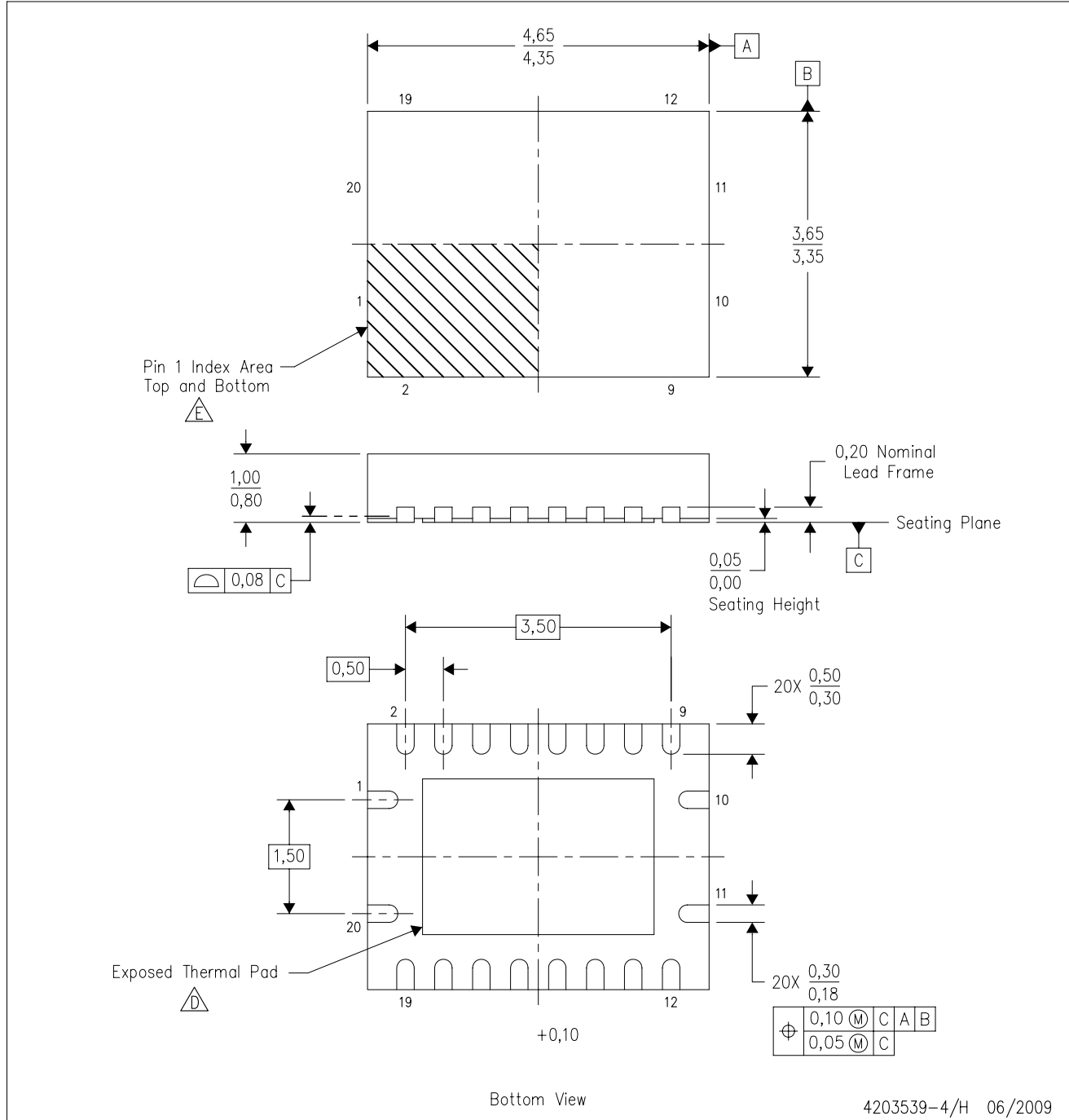
4203539−4/H 06/2009

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No−Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
E. Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
The Pin 1 identifiers are either a molded, marked, or metal feature.
F. Package complies to JEDEC MO−241 variation BC.

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RGY (R−PVQFN−N20)   PLASTIC QUAD FLATPACK NO−LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No−Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.
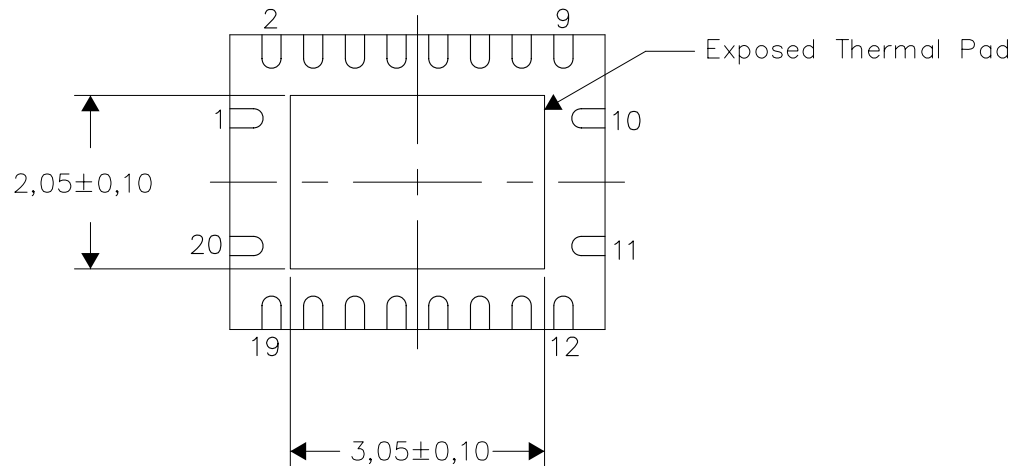
Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

4206353−4/L 08/10

RGY (R−PVQFN−N20)   PLASTIC QUAD FLATPACK NO−LEAD
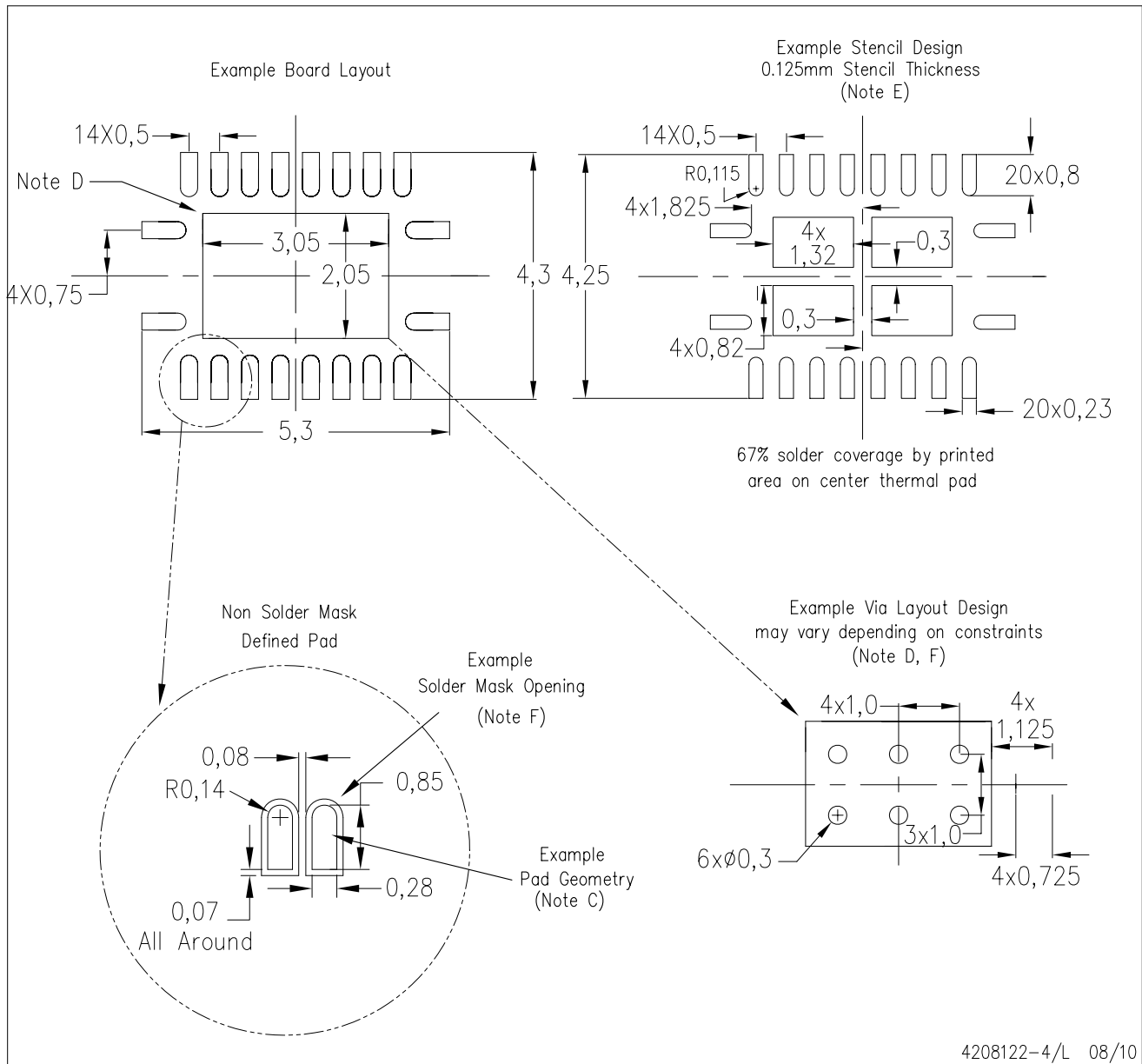
Example Board Layout

14X0,5

Note D

3,05

2,05

4,3 4,25

4X0,75

5,3

Example Stencil Design
0.125mm Stencil Thickness
(Note E)

14X0,5

R0,115

4x1,825

20x0,8

4x
1,32

0,3

0,3

4x0,82

20x0,23

67% solder coverage by printed
area on center thermal pad

Non Solder Mask
Defined Pad

Example
Solder Mask Opening
(Note F)

0,08

R0,14

0,85

0,07

0,28

All Around

Example
Pad Geometry
(Note C)

Example Via Layout Design
may vary depending on constraints
(Note D, F)

4x1,0

4x
1,125

6xØ0,3

3x1,0

4x0,725

4208122−4/L 08/10

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Publication IPC−7351 is recommended for alternate designs.
        D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat−Pack
            QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets
            for specific thermal information, via requirements, and recommended board layout.
            These documents are available at www.ti.com <http://www.ti.com>.
        E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
            contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
        F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

MECHANICAL DATA

NS (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN

DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

MECHANICAL DATA

DB (R-PDSO-G**)   **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN

PINS ** DIM	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
        D. Falls within JEDEC MO-150

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MECHANICAL DATA

PW (R-PDSO-G**)   **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN

0,65

0,30 / 0,19   ⊕ 0,10 Ⓜ

14   8

4,50 / 4,30   6,60 / 6,20

1   7

A

0,15 NOM

Gage Plane

0°–8°

0,25

0,75 / 0,50

1,20 MAX   0,15 / 0,05

Seating Plane   ◠ 0,10

DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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IMPORTANT NOTICE